

TC74ACT521P, TC74ACT521F, TC74ACT521FW

8-Bit Equality Comparator

The TC74ACT521 is an advanced high speed CMOS 8-BIT DIGITAL COMPARATOR fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

It compares two 8-bit binary or BCD words applied inputs P₀~P₇, and inputs Q₀~Q₇, and indicates whether or not they are equal.

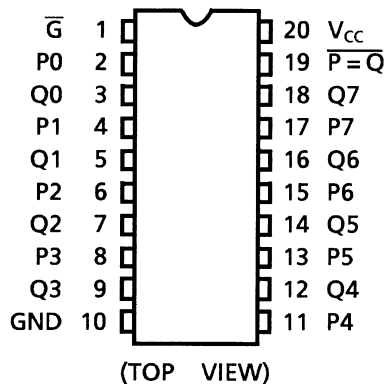
A signal active low enable is provided to facilitate cascading of several packages to compare of words greater than 8 bits.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

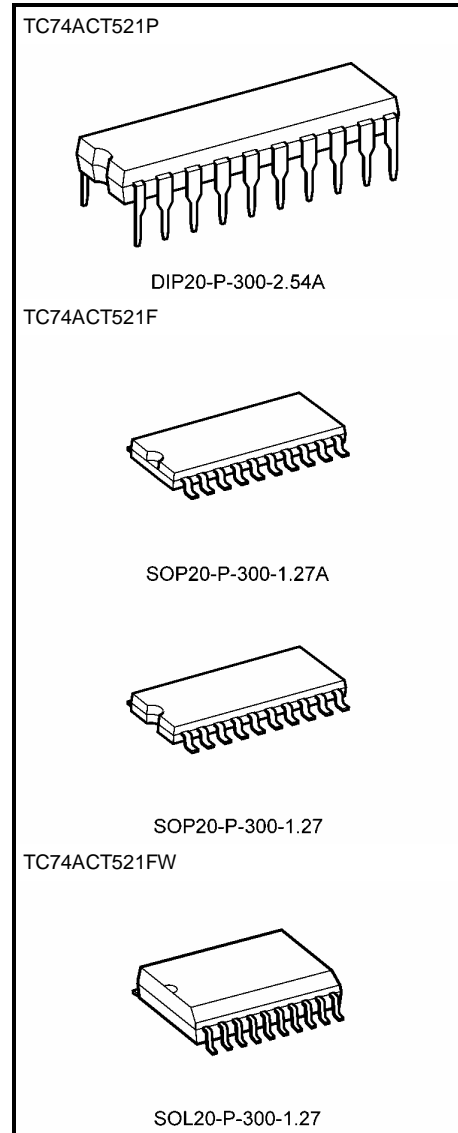
Features

- High speed: $t_{pd} = 6.4 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu\text{A (max)}$ at $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V (max)}$
 $V_{IH} = 2.0 \text{ V (min)}$
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24 \text{ mA (min)}$
Capability of driving 50Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74F521

Pin Assignment

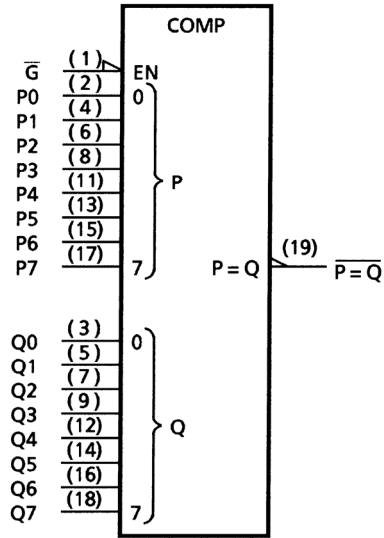


Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)

IEC Logic Symbol

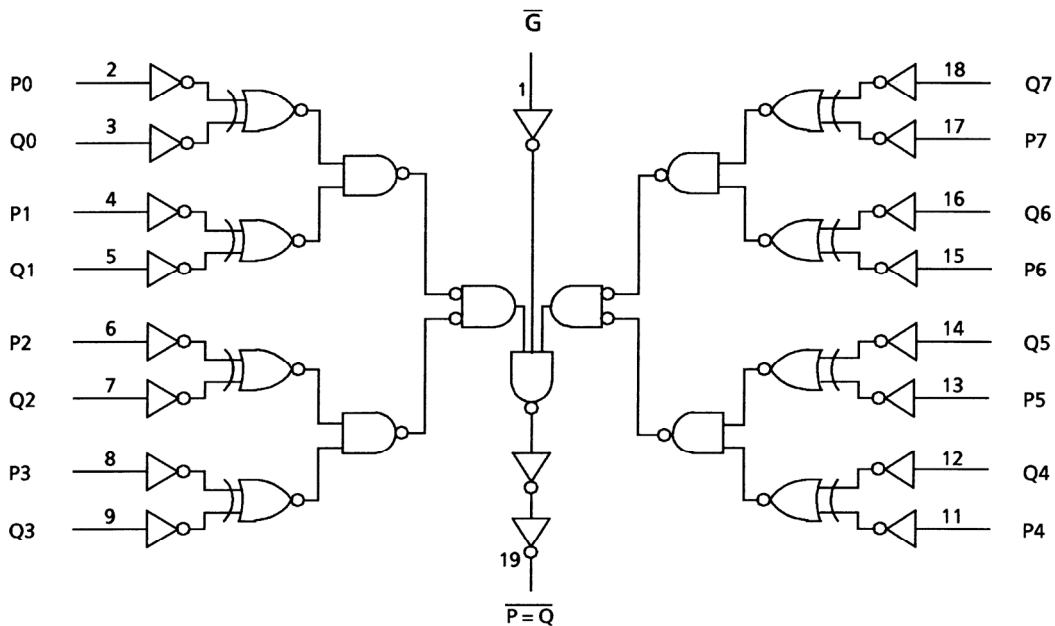


Truth Table

Inputs		Output
P, Q	\bar{G}	$\overline{P=Q}$
P = Q	L	L
P \neq Q	L	H
X	H	H

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5~7.0	V
DC input voltage	V_{IN}	-0.5~ $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5~ $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 50	mA
DC output current	I_{OUT}	± 50	mA
DC V_{CC} /ground current	I_{CC}	± 100	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	-65~150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of $T_a = -40\sim 65^\circ\text{C}$. From $T_a = 65$ to 85°C a derating factor of $-10\text{ mW}/^\circ\text{C}$ should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5~5.5	V
Input voltage	V_{IN}	0~ V_{CC}	V
Output voltage	V_{OUT}	0~ V_{CC}	V
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dV	0~10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	—		4.5~5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V _{IL}	—		4.5~5.5	—	—	0.8	—	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	4.5	—	4.4	—	V
			I _{OH} = -24 mA	4.5	3.94	—	—	3.80	—	
			I _{OH} = -75 mA (Note)	5.5	—	—	—	3.85	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	—	0.0	0.1	—	0.1	V
			I _{OL} = 24 mA	4.5	—	—	0.36	—	0.44	
			I _{OL} = 75 mA (Note)	5.5	—	—	—	—	1.65	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	8.0	—	80.0	μA
	I _C	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	—	—	1.35	—	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C_L = 50 pF, R_L = 500 Ω, input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
Propagation delay time (P _n , Q _n - $\overline{P=Q}$)	t _{pLH}	—		5.0 ± 0.5	—	7.1	11.4	1.0	13.0	ns
	t _{pHL}	—								
Propagation delay time ($\overline{G-P=Q}$)	t _{pLH}	—		5.0 ± 0.5	—	5.7	8.3	1.0	9.5	ns
	t _{pHL}	—								
Input capacitance	C _{IN}	—		—	5	10	—	10	pF	
Power dissipation capacitance (Note)	C _{PD}	—		—	29	—	—	—	pF	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

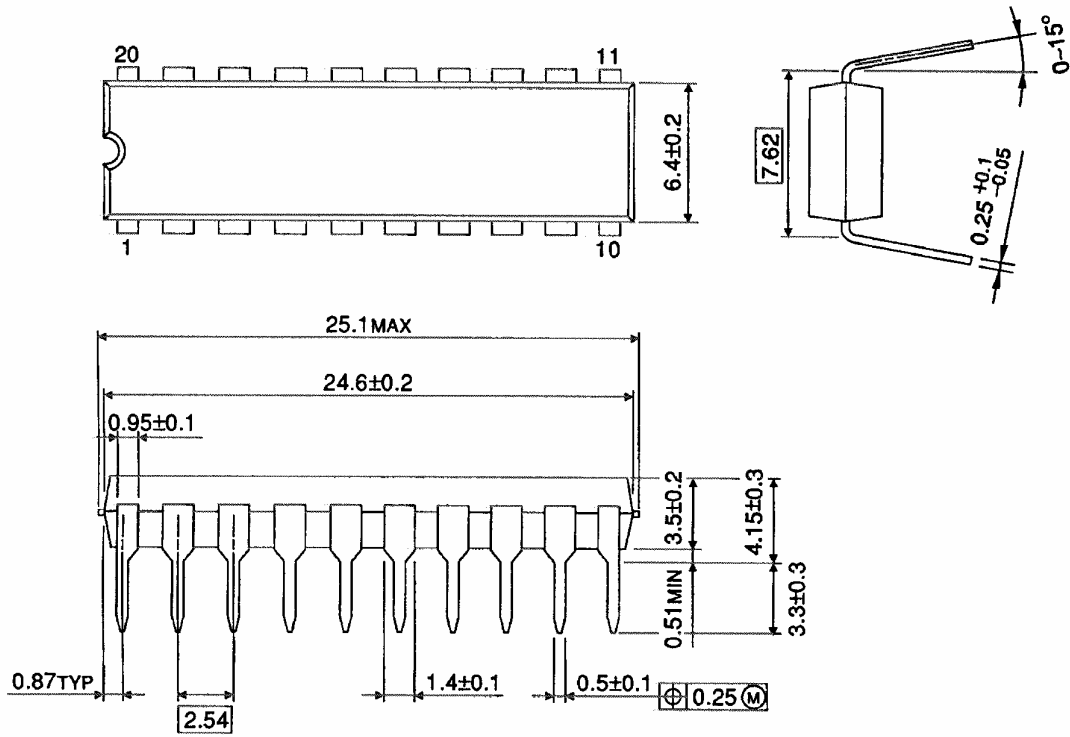
Average operating current can be obtained by the equation:

$$I_{CC} (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

DIP20-P-300-2.54A

Unit : mm

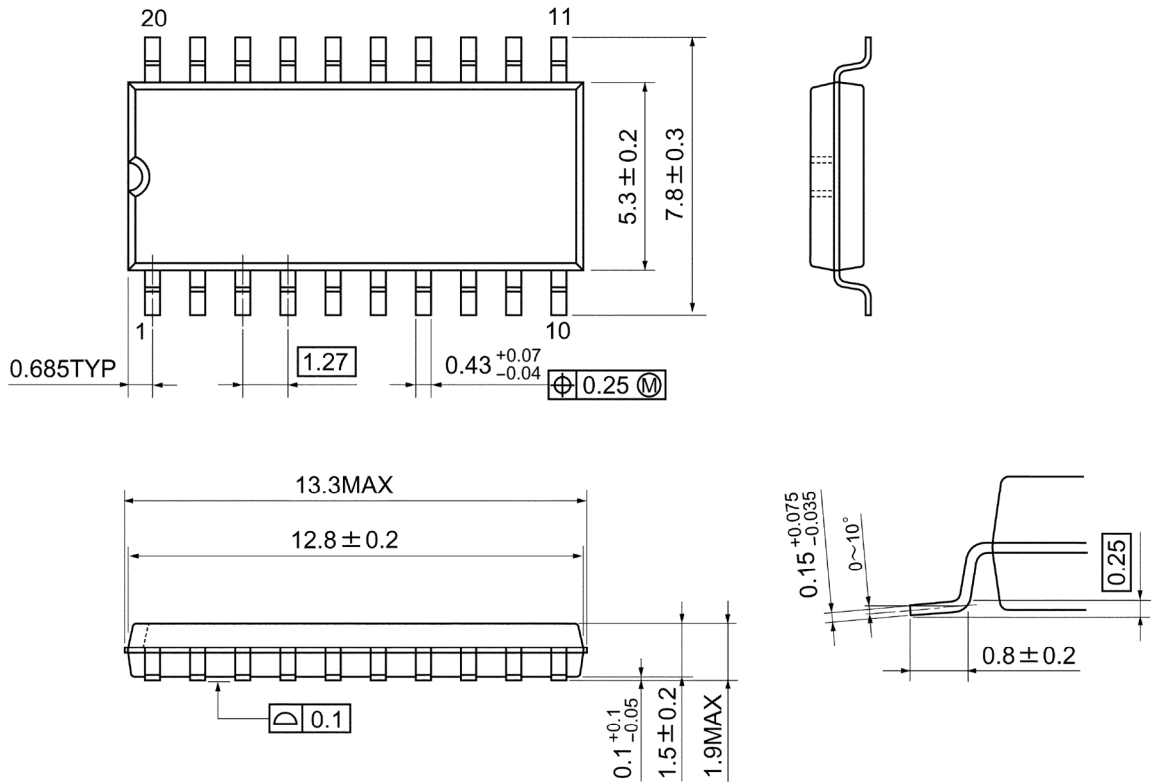


Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A

Unit: mm

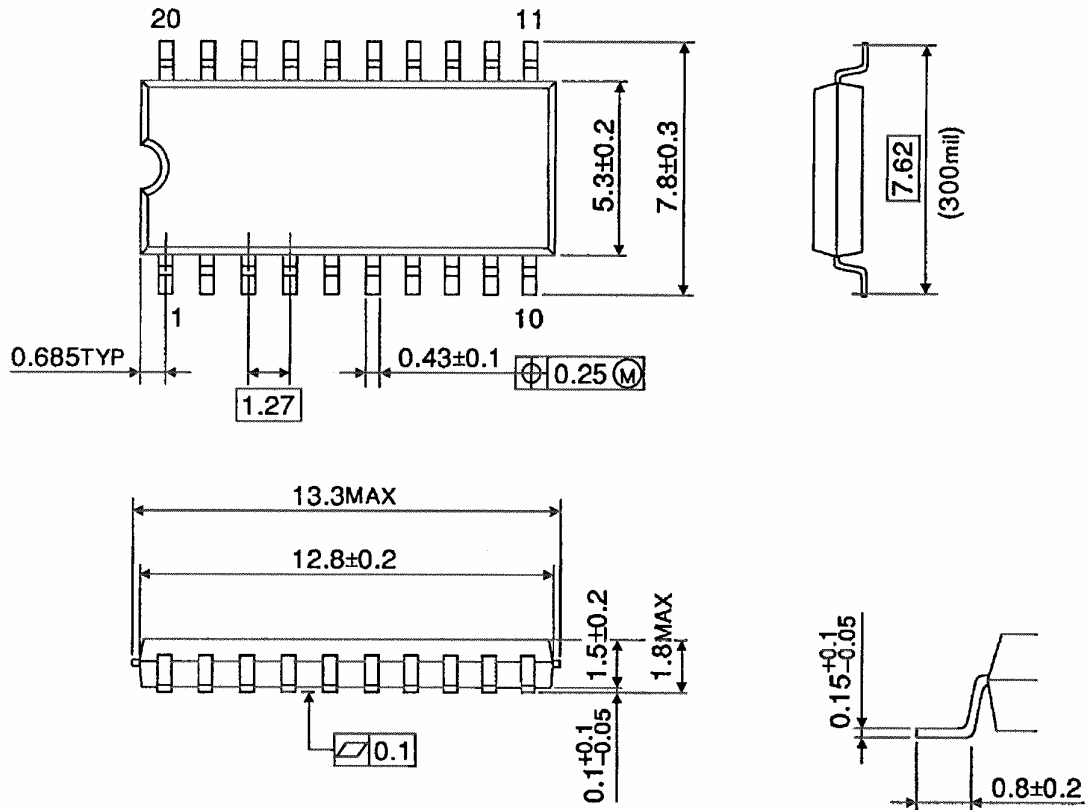


Weight: 0.22 g (typ.)

Package Dimensions

SOP20-P-300-1.27

Unit : mm

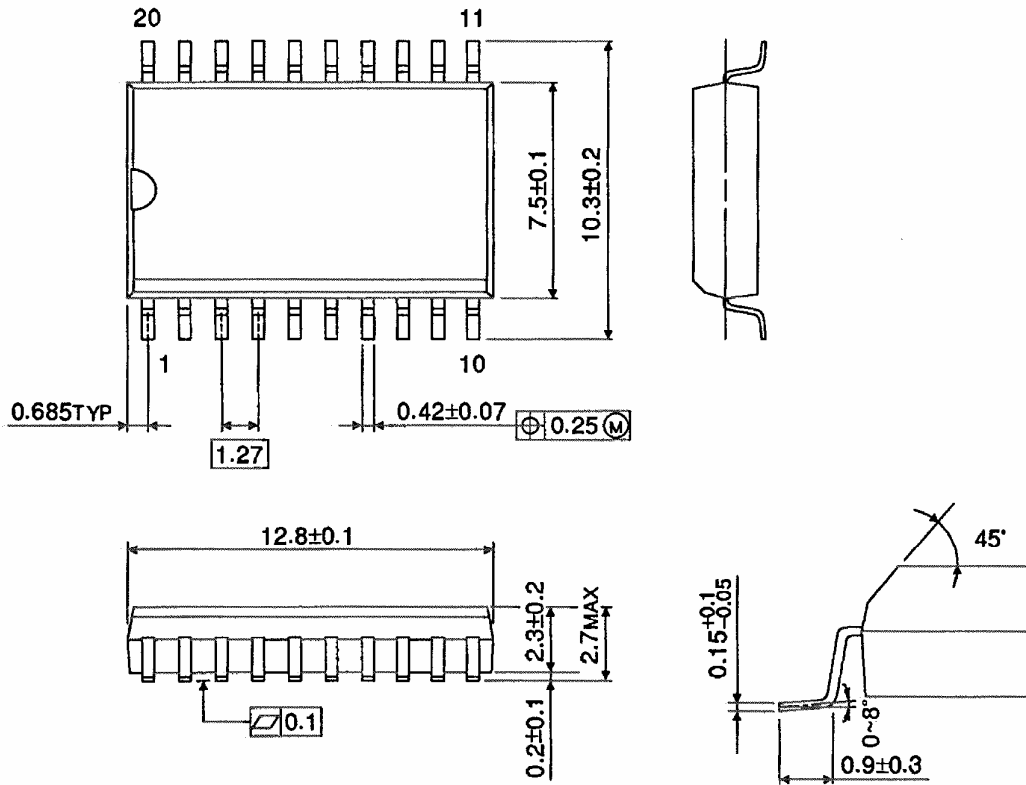


Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Note: Lead (Pb)-Free Packages**DIP20-P-300-2.54A SOP20-P-300-1.27A****RESTRICTIONS ON PRODUCT USE**

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